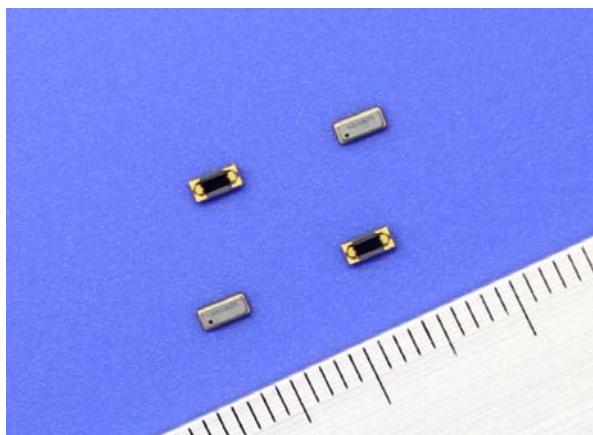


## High accuracy Crystal Oscillator 32.768kHz SH-32S



### Features

- Excellent frequency accuracy and Temperature characteristics
- Low current consumption
- Complete Pb-free
- Incorporated highly reliable photolithographic crystal resonator

### Applications

Smart Meter, IoT, Wearable device, Industry device, High precision timing device, Event data recorder, etc

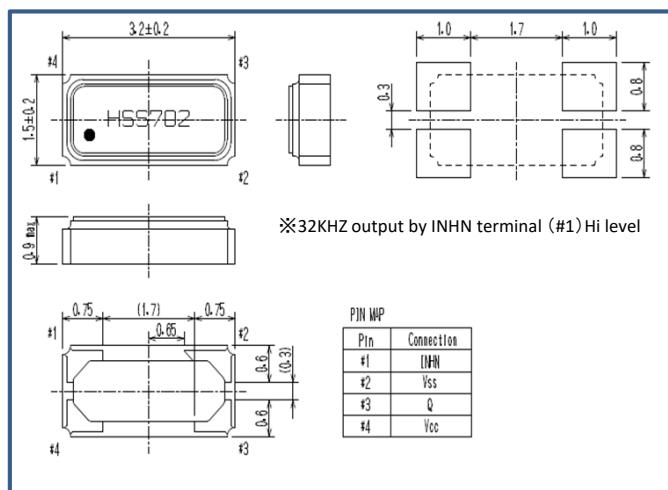
### Specifications

Item	Symbol	Specifications	Unit	Conditions Note
Nominal Frequency	f_nom	32.768	kHz	
Supply Voltage	Vcc	1.3~5.5	V	(*1)
Temperature Compensated Voltage	VTEM	2.0~5.5	V	
Storage temperature	T_stg	-55~+125	°C	
Operating temperature	T_use	-40~+85	°C	
Frequency tolerance	f_tol	±3	×10 <sup>-6</sup>	+25°C, VCC=3.3 V
Frequency temperature coefficient	f0_Tc	±50	×10 <sup>-6</sup>	-40~+85°C (+25°C is reference)
Frequency / voltage coefficient	f0_Vcc	±1	×10 <sup>-6</sup> /V	
Current consumption	Icc	1.0 Typ. 2.0 Max.	µA	3.3V, No load condition
Symmetry	SYM	50±10	%	Load: 15pF
Rise time / Fall time	tr/tf	50 Max.	ns	Load: 15pF output level 20~80%
Input voltage	VIL	20% Vcc Max.	V	INHN terminal
	VIH	80% Vcc Min.	V	INHN terminal
Output voltage	VOL	0.4 Max.	V	
	VOH	Vcc-0.4 Min.	V	
Output load condition (CMOS)	CLOUT	15 Max.	pF	CMOS Loading
Start-up time	t_str	0.5 Max.	sec	+25°C
Frequency aging	f_aging	±3	×10 <sup>-6</sup>	+25°C, Vcc=3.3V, First year

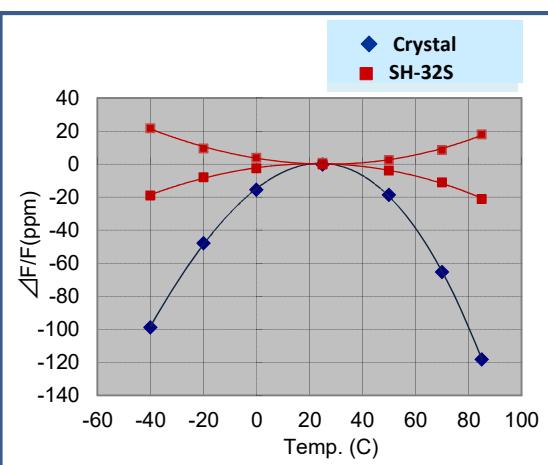
Unless otherwise stated, characteristics (specifications) shown in the above table are based on the rated operating temperature and voltage condition.

(\*1) When the supply voltage becomes below 2V, the frequency temperature compensation operation is inactivated.

### Dimensions



### Temperature characteristic



## Absolute maximum rating

Item	Symbol	Condition	Rated	Unit
Power Supply & Voltage range	Vcc	Between Vcc-Vss	-0.3~+6.5	V
Input Voltage range	Vin	Input terminal(INHN)	-0.3~Vcc+0.3	V
Output Voltage range	Vout	Output terminal(Q)	-0.3~Vcc+0.3	V
Output Power supply	Iout	Output terminal(Q)	±10	mA

※In order to run SH-32 stability, please be mounted Ceramic·Chip Condensor by more than 0.1μF near SH-32 between Vcc-Vss.

## Power consumption characteristics

Item	Symbol	Condition	MIN	TYP	MAX	Unit
Power consumption of starting (Temperature compensation interval in 2sec)	Icc	INHN=Vcc=3.3V,CLOUT=0pF Ta=-40°C~+85°C	—	1.0	2.0	μA
		INHN=Vcc=5.0V,CLOUT=0pF Ta=-40°C~+85°C	—	1.5	3.0	μA
Power consumption of booting	IBOOT	INHN=Vcc=3.3V,CLOUT=0pF Ta=-40°C~+85°C	—	1.5	2.5	μA
Power consumption of Disable	IDIS	INHN=Vss=0V,CLOUT=0pF Ta=-40°C~+85°C	—	0.6	1.5	μA

※In order to be short for oscillation starting time(t\_str), It is the power consumption booting when increased the oscillation drive capability. Booting circuit works until 0.5sec(t\_str+0.5s) from the power supply starting to oscillation starting.

## The function for INHN terminal

Input terminal(INHN)	Output terminal(Q)	Oscillation	Notes
"H" Level	32.768kHz output	Oscillation	—
"L" Level	Hi-Z	Oscillation	—
OPEN	—	—	Unavailable

## Frequency tolerance and Temperature characteristics

Temperature range(°C)	Frequency Tolerance ( $\times 10^{-6}$ )
0~+50	±20
-10~+60	±30
-20~+70	±40
-40~+85	±50

## The example for Circuit connection with MCU

